

International
IR Rectifier

IRKT152/04

THYRISTOR/ THYRISTOR

INT-A-pak™ Power Module

Features

- Electrically Isolated by DBC Ceramic (Al_2O_3)
- 3500 V_{RMS} Isolating Voltage
- Industrial Standard Package
- High Surge Capability
- Glass Passivated Chips
- Simple Mounting
- UL E78996 approved 

150 A

Applications

- Battery Charges
- Welders
- Power Converters

Major Ratings and Characteristics

Parameters	IRKT152/04	Units
$I_{T(AV)}$	150	A
@ T_C	85	°C
$I_{T(RMS)}$	330	A
I_{TSM} @ 50Hz	4000	
@ 60Hz	4200	
I^2t @ 50Hz	80	KA^2s
@ 60Hz	73	
I^2vt	800	KA^2Vs
V_{RRM}	400	V
T_{STG} range	-40 to 150	°C
T_J range	-40 to 125	

CASE STYLE NEW INT-A-PAK



ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	V_{RRM}/V_{DRM} , Maximum repetitive peak reverse voltage V	V_{RSM}/V_{DSM} , Maximum non-repetitive peak reverse voltage V	I_{RRM}/I_{DRM} @ 125°C mA
IRKT152/04	400	500	50

On-state Conduction

Parameter	IRKT152/04	Units	Conditions								
$I_{T(AV)}$ Max. average on-state current @ Case temperature	150	A	180° conduction half sine wave								
	85	°C									
$I_{T(RMS)}$ Maximum RMS on-state current	330	A	as AC switch								
I_{TSM} Maximum peak, one-cycle on-state, non-repetitive surge current	4000	A	t = 10ms	No voltage reapplied	Sine half wave, Initial $T_J = T_{J \max}$						
	4200		t = 8.3ms	100% V_{RRM} reapplied							
	3350		t = 10ms								
	3500		t = 8.3ms	100% V_{RRM} reapplied							
I^2t Maximum I^2t for fusing	80	KA ² s	t = 10ms	No voltage reapplied	Initial $T_J = T_{J \max}$						
	73		t = 8.3ms	100% V_{RRM} reapplied							
	56		t = 10ms								
	51		t = 8.3ms								
I^2v/t Maximum I^2v/t for fusing	800	KA ² v/s	t = 0.1 to 10ms, no voltage reapplied								
$V_{T(TO)}$ Value of threshold voltage	0.82	V	@ $T_J \max$.								
r_t On-state slope resistance	1.44	mΩ									
V_{TM} Maximum on-state voltage drop	1.48	V	$I_{pk} = \Pi \bullet I_{T(AV)}$, $T_J = 25^\circ\text{C}$								
I_H Maximum Holding Current	200	mA	$T_J = 25^\circ\text{C}$, anode supply = 6V, resistive load, gate open circuit								
I_L Maximum Latching Current	400		$T_J = 25^\circ\text{C}$, anode supply = 6V, resistive load								

Switching

t_{gd} Typical delay time	1	μs	$T_J = 25^\circ\text{C}$	Gate Current=1A $dIg/dt=1\text{A}/\mu\text{s}$
t_{gr} Typical rise time	2		$T_J = 25^\circ\text{C}$	$V_d=0.67\% V_{DRM}$
t_q Typical turn-off time	50 - 200		$I_{TM} = 300 \text{ A}$; $-dl/dt = 15 \text{ A}/\mu\text{s}$; $T_J = T_{J \max}$	$V_f = 50 \text{ V}$; $dV/dt = 20 \text{ V}/\mu\text{s}$; Gate 0 V, 100Ω

Blocking

I_{RRM} Maximum peak reverse and off-state leakage current	50	mA	$T_J = 125^\circ\text{C}$
V_{INS} RMS isolation voltage	3500	V	50Hz, circuit to base, all terminals shorted, $t = 1\text{s}$
dV/dt critical rate of rise of off-state voltage	1000	V/μs	$T_J = T_{J \max}$, exponential to 67% rated V_{DRM}

Triggering

Parameter	IRKT152/04	Units	Conditions	
P _{GM}	Max. peak gate power	12	W	t _p ≤5ms, T _J =T _J max.
P _{G(AV)}	Max. average gate power	3	W	f=50Hz, T _J =T _J max.
I _{GM}	Max. peak gate current	3	A	t _p ≤5ms, T _J =T _J max.
-V _{GT}	Max. peak negative gate voltage	10	V	T _J =T _J max.
V _{GT}	Max. required DC gate voltage to trigger	4	V	
		2.5		
		1.7		
I _{GT}	Max. required DC gate current to trigger	270	mA	T _J =-40°C Anode supply=6V, resistive load; Ra=1Ω
		150		T _J =25°C
		80		T _J =T _J max.
V _{GD}	Max. gate voltage that will not trigger	0.3	V	@ T _J =T _J max., rated V _{DRM} applied
I _{GD}	Max. gate current that will not trigger	10	mA	
di/dt	Max. rate of rise of turned-on current	300	A/μs	

Thermal and Mechanical Specifications

Parameter	IRKT152/04	Units	Conditions	
T _J	Max. junction operating temperature range	°C		
T _{stg}	Max. storage temperature range	°C		
R _{thJC}	Max. thermal resistance, junction to case	K/W	DC operation, per junction	
R _{thCS}	Max. thermal resistance, case to heatsink	K/W	Mounting surface smooth, flat and greased Per module	
T	IAP to heatsink	4 to 6	Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.
	torque ± 10% busbar to IAP	4 to 6		
wt	Approximate weight	200 (7.1)	g(oz)	
Case Style		New Int-A-Pak		

ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sinusoidal conduction @ T _J max.					Rectangular conduction @ T _J max.					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRKT152/04	0.007	0.010	0.013	0.016	0.017	0.009	0.012	0.014	0.016	0.017	K/W

IRKT152/04

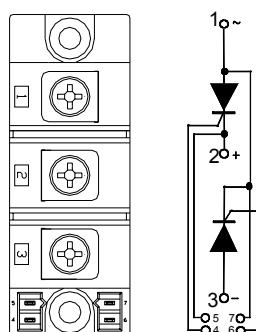
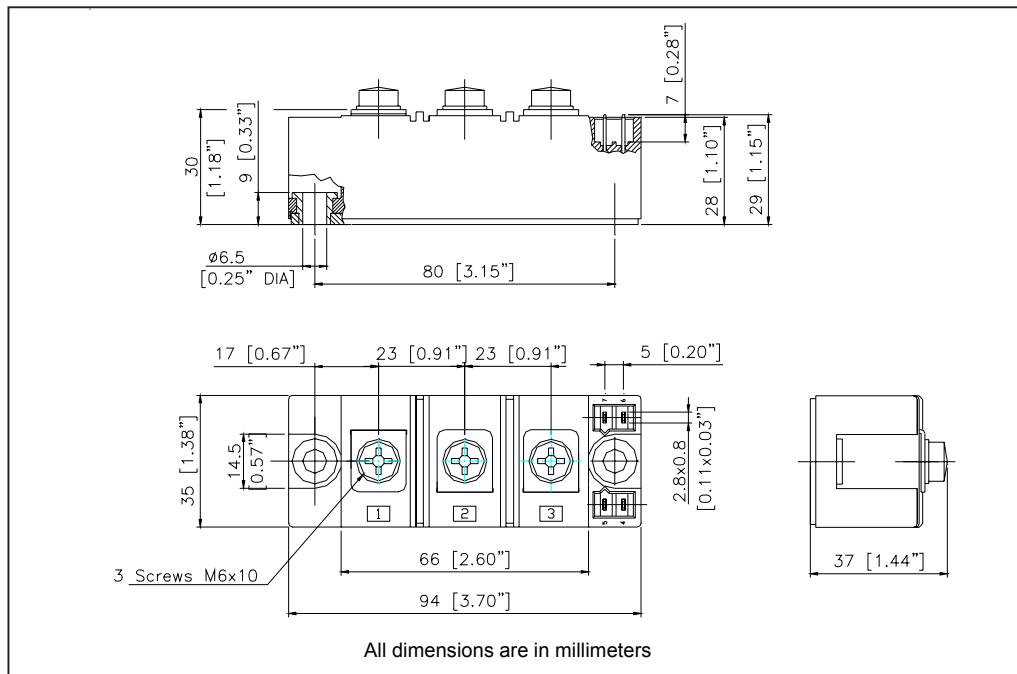
Bulletin I27122 rev. D 11/04

International
 **Rectifier**

Ordering Information Table

Device Code				
IRK	T	152	/	04
(1)	(2)	(3)		(4)
1	- Module Type			
2	- Circuit Configuration			
3	- Current Rating			
4	- Voltage Rating (04 = 400V)			

Outline Table



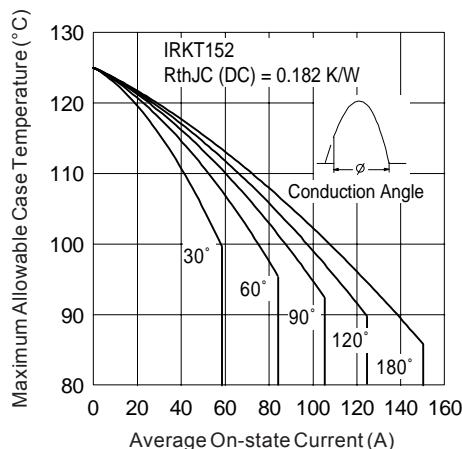


Fig. 1 - Current Ratings Characteristics

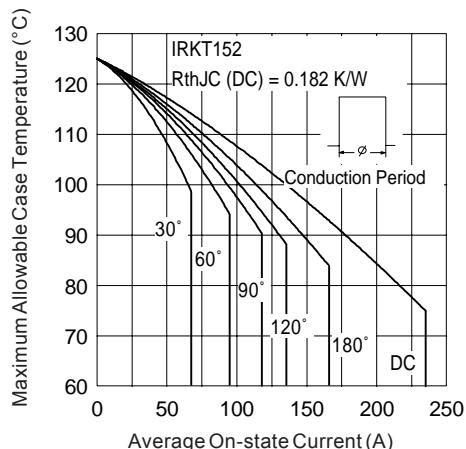


Fig. 2 - Current Ratings Characteristics

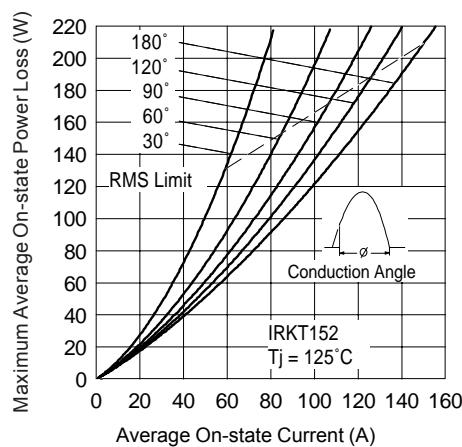


Fig. 3 - Forward Power Loss Characteristics

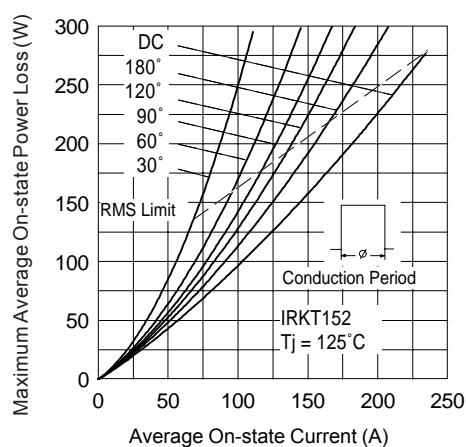


Fig. 4 - Forward Power Loss Characteristics

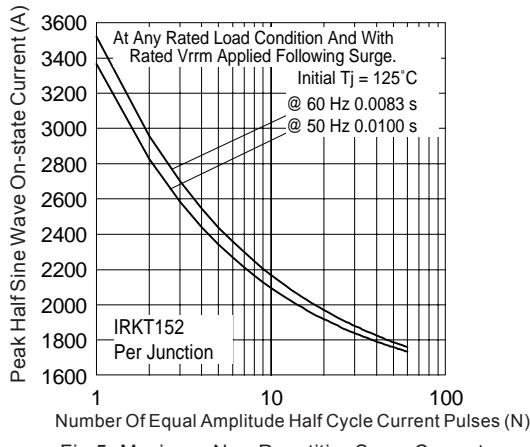


Fig. 5 - Maximum Non-Repetitive Surge Current

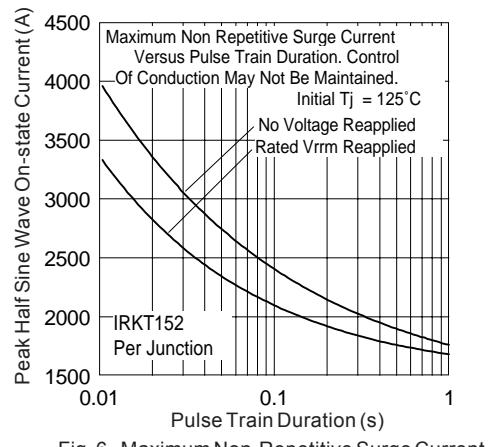


Fig. 6 - Maximum Non-Repetitive Surge Current

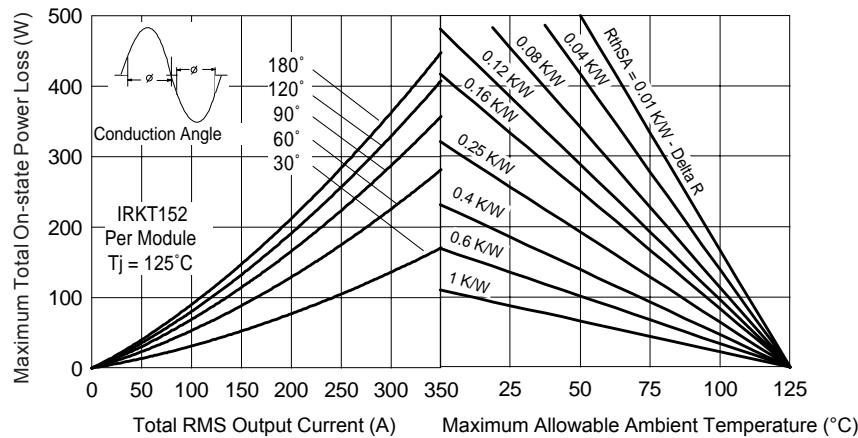


Fig.7 - On State Power Loss Characteristics

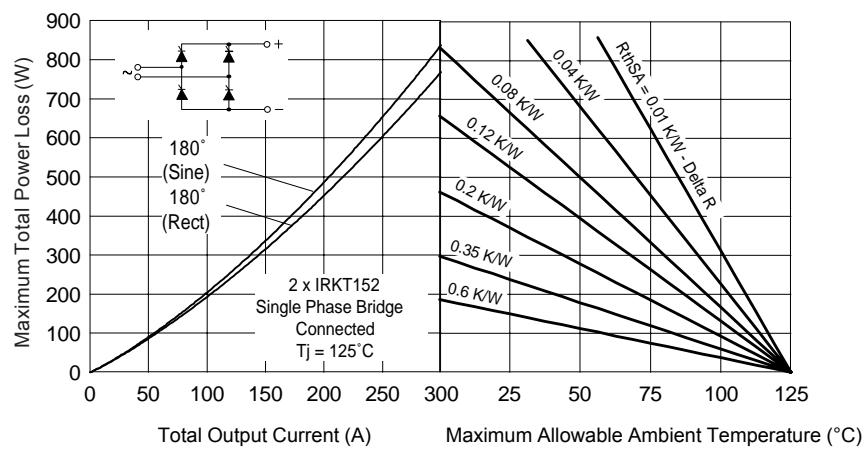


Fig.8 - On State Power Loss Characteristics

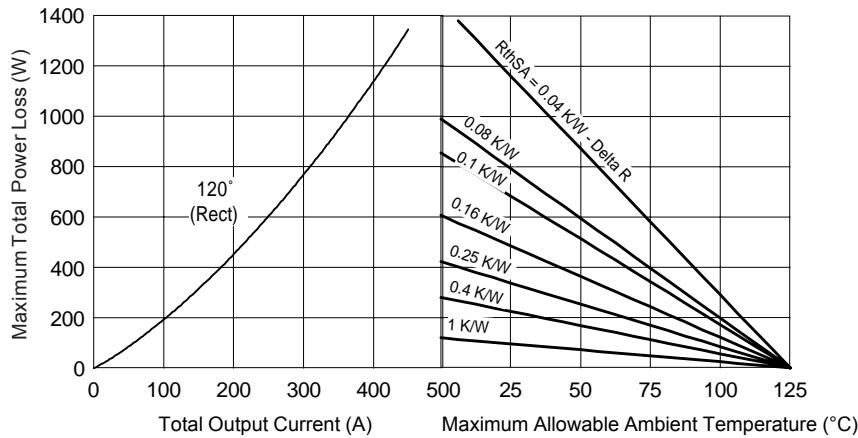


Fig. 9 - On State Power Loss Characteristics

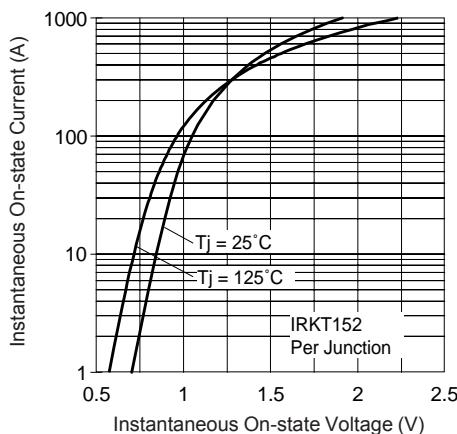


Fig. 10 - On-State Voltage Drop Characteristics

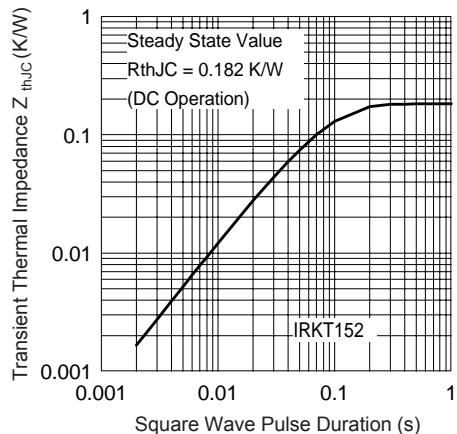


Fig. 11 - Thermal Impedance ZthJC Characteristics

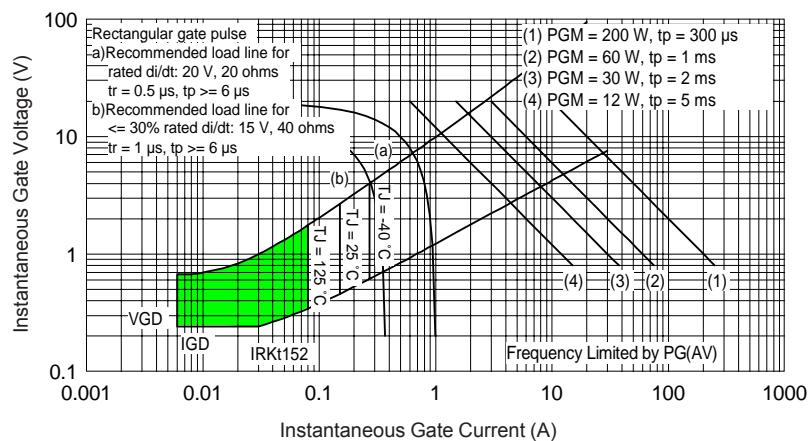


Fig. 12 - Gate Characteristics

Data and specifications subject to change without notice.
This product has been designed and qualified for Multiple Level Qualification Standards can be found on IR's Web site.

International
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11/04



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